TOSHIBA LED LAMP InGaA&P YELLOW LIGHT EMISSION

TLYE261AP

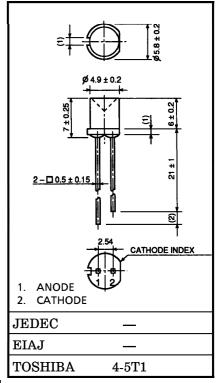
PANEL CIRCUIT INDICATOR

- 5 mm DIAMETER
- InGaA&P YELLOW LED
- All Plastic Mold Type.
- Colorless Clear Lens
- Low Drive Current, High Intensity Yellow Light Emission Recommended Forward Current : I_F = 15~20 mA (DC)
- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio.
- Fast Response Time, Capable of Pulse Operation.
- High Power Luminous Intensity
- Without stand-offs
- Wide Radiation Pattern.
- APPLICATIONS: Suitable for Backlighting.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current (DC)	$I_{\mathbf{F}}$	50	mA
Reverse Voltage	v_{R}	4	V
Power Dissipation	$P_{\mathbf{D}}$	125	mW
Operating Temperature Range	${ m T_{opr}}$	-30~85	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~120	$^{\circ}\mathrm{C}$

Unit in mm



Weight: $0.26\,\mathrm{g}$

2001-06-01

ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta = 25°C)

CHAR	RACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Forward V	oltage	$ m V_{ m F}$	$I_{ m F}=20{ m mA}$	_	2.1	2.5	V
Reverse Cu	ırrent	${ m I_R}$	$V_R = 4 V$	_	_	50	μ A
Luminous	TLYE261AP	- I _V	$I_{\mathrm{F}} = 20 \mathrm{mA} \mathrm{(Note)}$	8.5	27	_	mcd
Intensity	TLYE261AP (JK)			8.5	_	41.4	
Peak Emis	sion Wavelength	$\lambda_{\mathbf{p}}$	$I_{ m F}=20{ m mA}$	_	590	_	nm
Spectral Li	ne Half Width	Δλ	$I_{ m F}=20{ m mA}$	_	13	_	nm
Dominant	Wavelength	$^{\lambda}\mathrm{d}$	$I_{ m F}=20{ m mA}$	_	587	_	nm

(Note): Lamps are classified into the following ranks according to their luminous intensity.

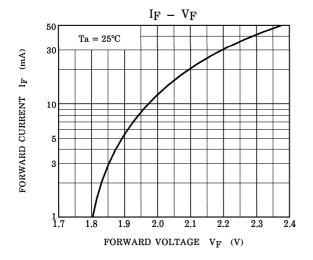
Measurement tolerance for each limit is $\pm 15\%$. J: 10-20 mcd, K: 18-36 mcd, L: 32-64 mcd.

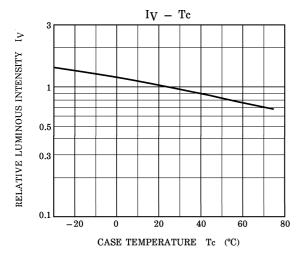
PRECAUTION

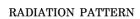
Please be careful of the followings

- Soldering temperature: 260°C max Soldering time: 3 s max (Soldering portion of lead: up to 2 mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5 mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.
- This visible LED lamp also emits some IR light. If a photodetector is located near the LED lamp, please ensure that it will not be affected by this IR light.

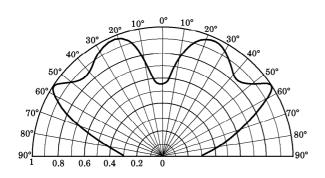
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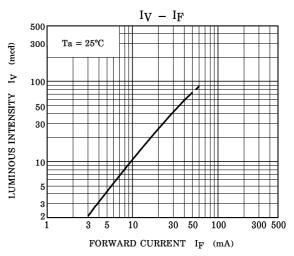


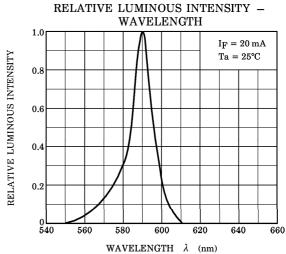


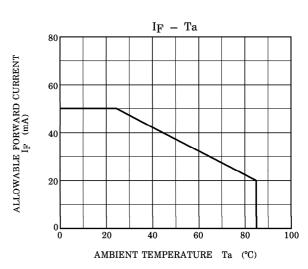


 $Ta = 25^{\circ}C$









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RESTRICTIONS ON PRODUCT USE

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